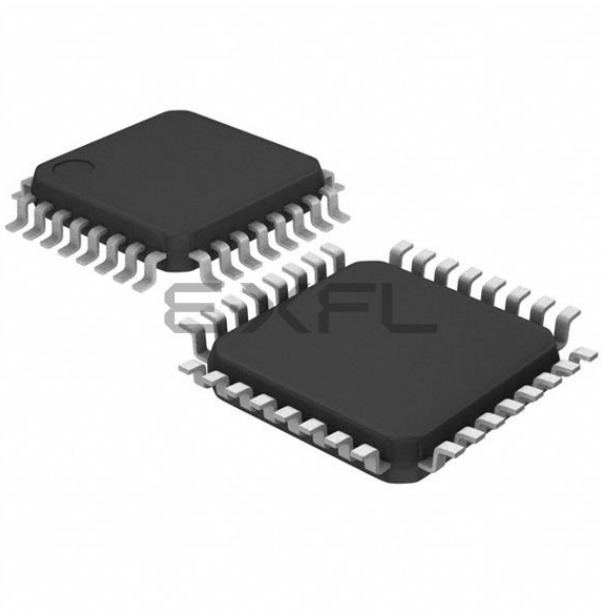

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Discontinued at Digi-Key
Core Processor	CIP-51 8051
Core Size	8-Bit
Speed	25MHz
Connectivity	EBI/EMI, I²C, SMBus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	24
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4.25K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 23x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-QFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm8sb20f32g-a-qfp32

1. Feature List

The EFM8SB2 highlighted features are listed below.

- Core:
  - Pipelined CIP-51 Core
  - Fully compatible with standard 8051 instruction set
  - 70% of instructions execute in 1-2 clock cycles
  - 25 MHz maximum operating frequency
- Memory:
  - Up to 64 kB flash memory, in-system re-programmable from firmware.
  - Up to 4352 bytes RAM (including 256 bytes standard 8051 RAM and 4096 bytes on-chip XRAM)
- Power:
  - Internal LDO regulator for CPU core voltage
  - Power-on reset circuit and brownout detectors
- I/O: Up to 24 total multifunction I/O pins:
  - Flexible peripheral crossbar for peripheral routing
  - 5 mA source, 12.5 mA sink allows direct drive of LEDs
- Clock Sources:
  - Internal 20 MHz low power oscillator with ±10% accuracy
  - Internal 24.5 MHz precision oscillator with ±2% accuracy
  - External RTC 32 kHz crystal
  - External crystal, RC, C, and CMOS clock options
- Timers/Counters and PWM:
  - 32-bit Real Time Clock (RTC)
  - 6-channel programmable counter array (PCA) supporting PWM, capture/compare, and frequency output modes with watchdog timer function
  - 4 x 16-bit general-purpose timers
- Communications and Digital Peripherals:
  - UART
  - 2 x SPI™ Master / Slave
  - SMBus™/I2C™ Master / Slave
  - External Memory Interface (EMIF)
  - 16-bit/32-bit CRC unit, supporting automatic CRC of flash at 1024-byte boundaries
- Analog:
  - Programmable current reference (IREF0)
  - 10-Bit Analog-to-Digital Converter (ADC0)
  - 2 x Low-current analog comparators
- On-Chip, Non-Intrusive Debugging
  - Full memory and register inspection
  - Four hardware breakpoints, single-stepping
- Pre-loaded UART bootloader
- Temperature range -40 to 85 ºC
- Single power supply 1.8 to 3.6 V
- QFP32, QFN32, and QFN24 packages

With on-chip power-on reset, voltage supply monitor, watchdog timer, and clock oscillator, the EFM8SB2 devices are truly standalone system-on-a-chip solutions. The flash memory is reprogrammable in-circuit, providing non-volatile data storage and allowing field upgrades of the firmware. The on-chip debugging interface (C2) allows non-intrusive (uses no on-chip resources), full speed, in-circuit debugging using the production MCU installed in the final application. This debug logic supports inspection and modification of memory and registers, setting breakpoints, single stepping, and run and halt commands. All analog and digital peripherals are fully functional while debugging. Each device is specified for 1.8 to 3.6 V operation and is available in 24-pin QFN, 32-pin QFN, or 32-pin QFP packages. All package options are lead-free and RoHS compliant.

Ordering Part Number	Flash Memory (kB)	RAM (Bytes)	Digital Port I/Os (Total)	ADC Channels	Comparator Inputs	Pb-free (RoHS Compliant)	Temperature Range	Package
EFM8SB20F16G-A-QFN24	16	4352	16	15	8	Yes	-40 to +85 C	QFN24

3. System Overview

3.1 Introduction

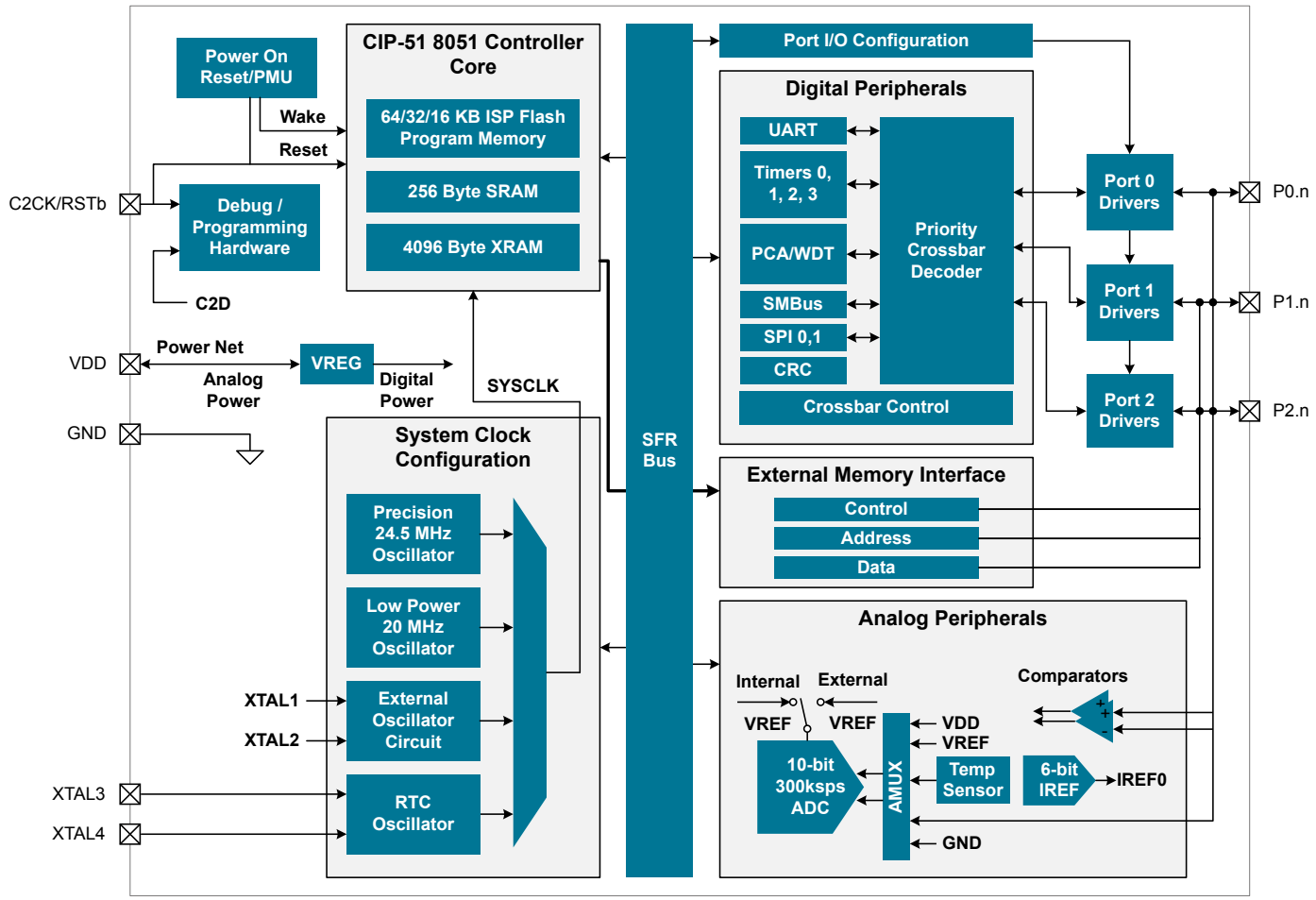

Figure 3.1. Detailed EFM8SB2 Block Diagram

3.5 Counters/Timers and PWM

Real Time Clock (RTC0)

The RTC is an ultra low power, 36 hour 32-bit independent time-keeping Real Time Clock with alarm. The RTC has a dedicated 32 kHz oscillator. No external resistor or loading capacitors are required, and a missing clock detector features alerts the system if the external crystal fails. The on-chip loading capacitors are programmable to 16 discrete levels allowing compatibility with a wide range of crystals.

The RTC module includes the following features:

- Up to 36 hours (32-bit) of independent time keeping.
- Support for external 32 kHz crystal or internal self-oscillate mode.
- Internal crystal loading capacitors with 16 levels.
- Operation in the lowest power mode and across the full supported voltage range.
- Alarm and oscillator failure events to wake from the lowest power mode or reset the device.

Programmable Counter Array (PCA0)

The programmable counter array (PCA) provides multiple channels of enhanced timer and PWM functionality while requiring less CPU intervention than standard counter/timers. The PCA consists of a dedicated 16-bit counter/timer and one 16-bit capture/compare module for each channel. The counter/timer is driven by a programmable timebase that has flexible external and internal clocking options. Each capture/compare module may be configured to operate independently in one of five modes: Edge-Triggered Capture, Software Timer, High-Speed Output, Frequency Output, or Pulse-Width Modulated (PWM) Output. Each capture/compare module has its own associated I/O line (CEXn) which is routed through the crossbar to port I/O when enabled.

- 16-bit time base.
- Programmable clock divisor and clock source selection.
- Up to six independently-configurable channels
- 8, 9, 10, 11 and 16-bit PWM modes (edge-aligned operation).
- Frequency output mode.
- Capture on rising, falling or any edge.
- Compare function for arbitrary waveform generation.
- Software timer (internal compare) mode.
- Integrated watchdog timer.

Timers (Timer 0, Timer 1, Timer 2, and Timer 3)

Several counter/timers are included in the device: two are 16-bit counter/timers compatible with those found in the standard 8051, and the rest are 16-bit auto-reload timers for timing peripherals or for general purpose use. These timers can be used to measure time intervals, count external events and generate periodic interrupt requests. Timer 0 and Timer 1 are nearly identical and have four primary modes of operation. The other timers offer both 16-bit and split 8-bit timer functionality with auto-reload and capture capabilities.

Timer 0 and Timer 1 include the following features:

- Standard 8051 timers, supporting backwards-compatibility with firmware and hardware.
- Clock sources include SYSCLK, SYSCLK divided by 12, 4, or 48, the External Clock divided by 8, or an external pin.
- 8-bit auto-reload counter/timer mode
- 13-bit counter/timer mode
- 16-bit counter/timer mode
- Dual 8-bit counter/timer mode (Timer 0)

Timer 2 and Timer 3 are 16-bit timers including the following features:

- Clock sources include SYSCLK, SYSCLK divided by 12, or the External Clock divided by 8.
- 16-bit auto-reload timer mode
- Dual 8-bit auto-reload timer mode
- Comparator 0 or RTC0 capture (Timer 2)
- Comparator 1 or EXTCLK/8 capture (Timer 3)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Temperature Coefficient	TC_{REFFS}		—	50	—	ppm/°C
Turn-on Time	t_{VREFFS}		—	—	1.5	µs
Power Supply Rejection	$PSRR_{REFFS}$		—	400	—	ppm/V
On-chip Precision Reference						
Output Voltage	V_{REFP}		1.645	1.68	1.715	V
Turn-on Time, settling to 0.5 LSB	t_{VREFP}	4.7 µF tantalum + 0.1 µF ceramic bypass on VREF pin	—	15	—	ms
		0.1 µF ceramic bypass on VREF pin	—	300	—	µs
		No bypass on VREF pin	—	25	—	µs
Load Regulation	LR_{VREFP}	Load = 0 to 200 µA to GND	—	400	—	µV / µA
Short-circuit current	ISC_{VREFP}		—	3.5	—	mA
Power Supply Rejection	$PSRR_{VREFP}$		—	140	—	ppm/V
External Reference						
Input Voltage	V_{EXTREF}		1	—	V_{DD}	V
Input Current	I_{EXTREF}	Sample Rate = 300 ksps; VREF = 3.0 V	—	5.25	—	µA

Table 4.11. Temperature Sensor

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Offset	V_{OFF}	T_A = 0 °C	—	940	—	mV
Offset Error[1]	E_{OFF}	T_A = 0 °C	—	18	—	mV
Slope	M		—	3.40	—	mV/°C
Slope Error[1]	E_M		—	40	—	µV/°C
Linearity			—	±1	—	°C
Turn-on Time	t_{PWR}		—	1.8	—	µs

Note:
1. Represents one standard deviation from the mean.

Table 4.12. Comparators

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Response Time, CPMD = 00 (Highest Speed)	t_{RESP0}	+100 mV Differential	—	130	—	ns
		–100 mV Differential	—	200	—	ns
Response Time, CPMD = 11 (Lowest Power)	t_{RESP3}	+100 mV Differential	—	1.75	—	µs
		–100 mV Differential	—	6.2	—	µs

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Input Offset Tempco	TC_{OFF}		—	3.5	—	µV/°C

Table 4.13. Programmable Current Reference (IREF0)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Performance						
Resolution	N_{bits}			6		bits
Output Compliance Range	V_{IOUT}	Low Power Mode, Source	0	—	V_{DD} – 0.4	V
		High Current Mode, Source	0	—	V_{DD} – 0.8	V
		Low Power Mode, Sink	0.3	—	V_{DD}	V
		High Current Mode, Sink	0.8	—	V_{DD}	V
Integral Nonlinearity	INL		—	<±0.2	±1.0	LSB
Differential Nonlinearity	DNL		—	<±0.2	±1.0	LSB
Offset Error	E_{OFF}		—	<±0.1	±0.5	LSB
Full Scale Error	E_{FS}	Low Power Mode, Source	—	—	±5	%
		High Current Mode, Source	—	—	±6	%
		Low Power Mode, Sink	—	—	±8	%
		High Current Mode, Sink	—	—	±8	%
Absolute Current Error	E_{ABS}	Low Power Mode Sourcing 20 µA	—	<±1	±3	%
Dynamic Performance						
Output Settling Time to 1/2 LSB	t_{SETTLE}		—	300	—	ns
Startup Time	t_{PWR}		—	1	—	µs

Note:
1. The PCA block may be used to improve IREF0 resolution by PWMing the two LSBs.

Table 4.14. Port I/O

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output High Voltage (High Drive)	V_{OH}	I_{OH} = –3 mA	V_{DD} – 0.7	—	—	V
Output Low Voltage (High Drive)	V_{OL}	I_{OL} = 8.5 mA	—	—	0.6	V
Output High Voltage (Low Drive)	V_{OH}	I_{OH} = –1 mA	V_{DD} – 0.7	—	—	V
Output Low Voltage (Low Drive)	V_{OL}	I_{OL} = 1.4 mA	—	—	0.6	V
Input High Voltage	V_{IH}	V_{DD} = 2.0 to 3.6 V	V_{DD} – 0.6	—	—	V
		V_{DD} = 1.8 to 2.0 V	0.7 x V_{DD}	—	—	V
Input Low Voltage	V_{IL}	V_{DD} = 2.0 to 3.6 V	—	—	0.6	V
		V_{DD} = 1.8 to 2.0 V	—	—	0.3 x V_{DD}	V

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Weak Pull-Up Current	I_{PU}	V_{DD} = 1.8 V V_{IN} = 0 V	—	–4	—	µA
		V_{DD} = 3.6 V V_{IN} = 0 V	–35	–20	—	µA
Input Leakage	I_{LK}	Weak pullup disabled or pin in analog mode	–1	—	1	µA

4.2 Thermal Conditions

Table 4.15. Thermal Conditions

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Thermal Resistance[1]	θ_{JA}	QFN-24 Packages	—	35	—	°C/W
		QFN-32 Packages	—	28	—	°C/W
		QFP-32 Packages	—	80	—	°C/W

Note:
1. Thermal resistance assumes a multi-layer PCB with any exposed pad soldered to a PCB pad.

4.3 Absolute Maximum Ratings

Stresses above those listed in Table 4.16 Absolute Maximum Ratings on page 19 may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. For more information on the available quality and reliability data, see the Quality and Reliability Monitor Report at http://www.silabs.com/support/quality/pages/default.aspx.

Table 4.16. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Max	Unit
Ambient Temperature Under Bias	T_{BIAS}		–55	125	°C
Storage Temperature	T_{STG}		–65	150	°C
Voltage on V_{DD}	V_{DD}		GND–0.3	4.0	V
Voltage on I/O pins or RSTb	V_{IN}	V_{DD} > 2.2 V	GND–0.3	5.8	V
		V_{DD} <= 2.2 V	GND–0.3	V_{DD} + 3.6	V
Total Current Sunk into Supply Pin	I_{VDD}		—	400	mA
Total Current Sourced out of Ground Pin	I_{GND}		400	—	mA
Current Sourced or Sunk by Any I/O Pin or RSTb	I_{IO}		-100	100	mA
Maximum Total Current through all Port Pins	I_{IOTOT}		—	200	mA
Operating Junction Temperature	T_J		–40	105	°C
Exposure to maximum rating conditions for extended periods may affect device reliability.					

4.4 Typical Performance Curves

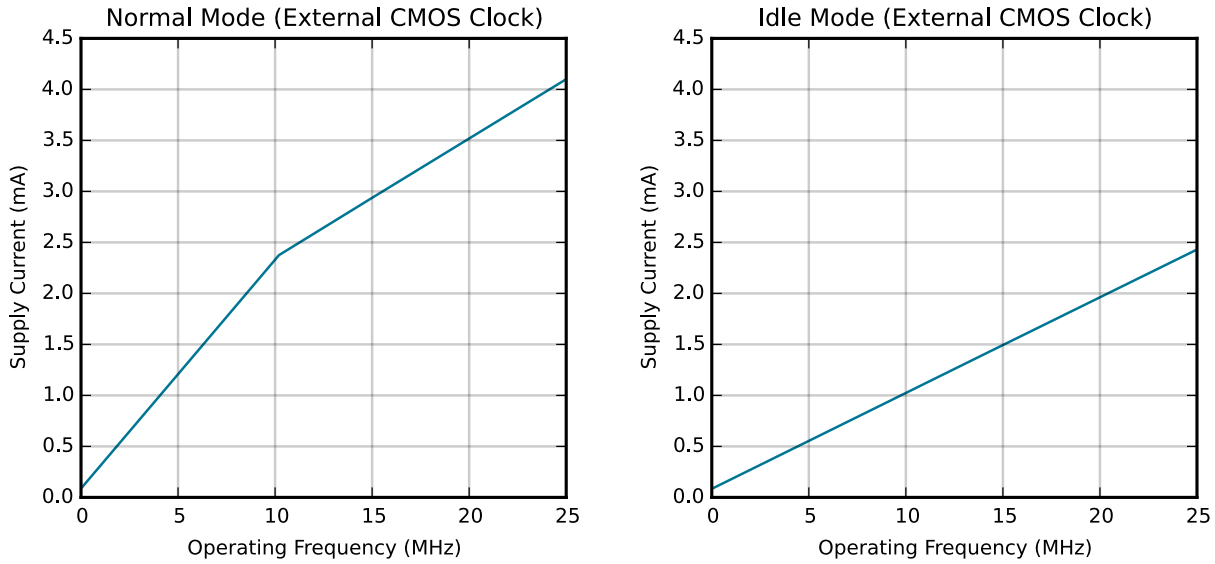

Figure 4.1. Typical Operating Supply Current (full supply voltage range)

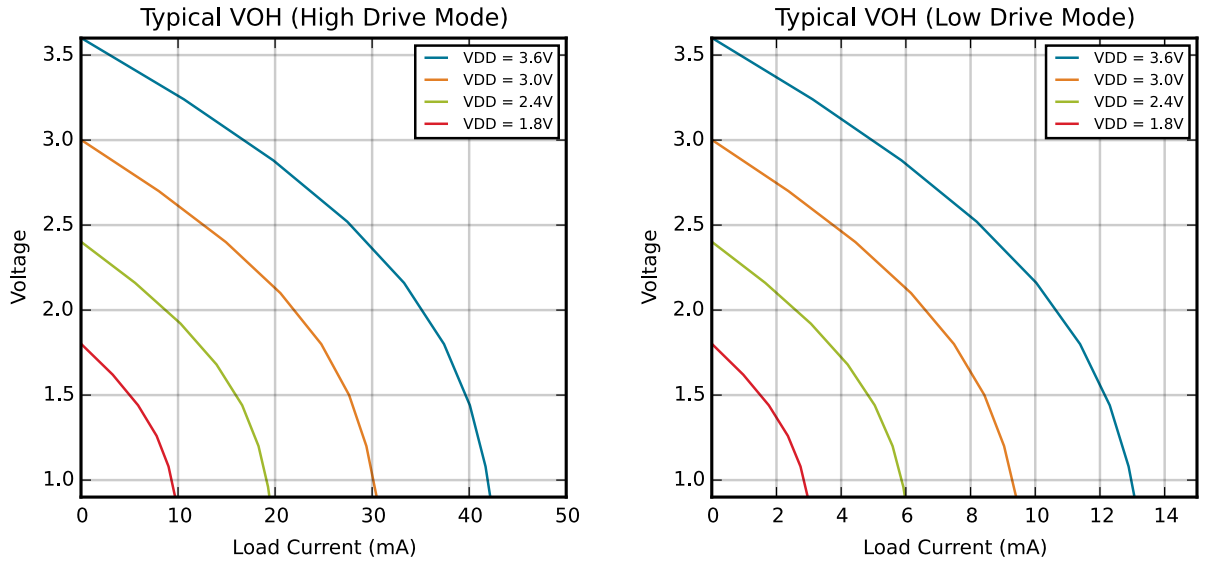

Figure 4.2. Typical V_{OH} Curves

5. Typical Connection Diagrams

5.1 Power

Figure 5.1 Power Connection Diagram on page 22 shows a typical connection diagram for the power pins of the EFM8SB2 devices.

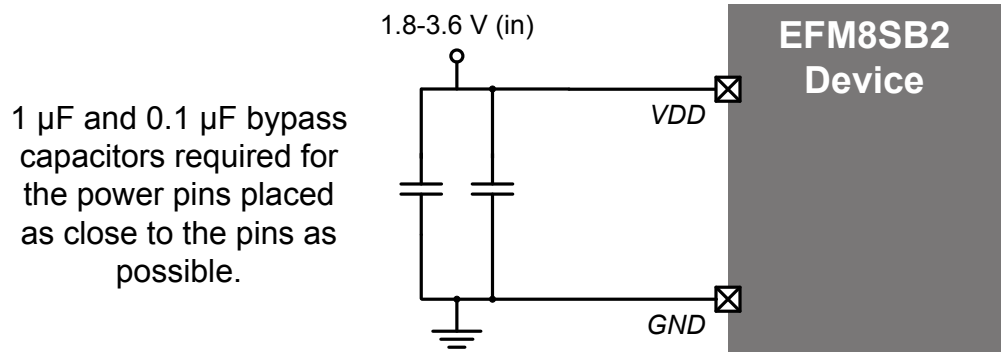

Figure 5.1. Power Connection Diagram

5.2 Other Connections

Other components or connections may be required to meet the system-level requirements. Application Note AN203: "8-bit MCU Printed Circuit Board Design Notes" contains detailed information on these connections. Application Notes can be accessed on the Silicon Labs website (www.silabs.com/8bit-appnotes).

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
5	N/C	No Connection			
6	RSTb / C2CK	Active-low Reset / C2 Debug Clock			
7	P2.7 / C2D	Multifunction I/O / C2 Debug Data			
8	P2.6	Multifunction I/O	Yes	EMIF_WRb	ADC0.22 CMP0P.11 CMP1P.11
9	XTAL4	RTC Crystal			XTAL4
10	XTAL3	RTC Crystal			XTAL3
11	P2.5	Multifunction I/O	Yes	EMIF_RDb	ADC0.21 CMP0N.10 CMP1N.10
12	P2.4	Multifunction I/O	Yes	EMIF_ALE	ADC0.20 CMP0P.10 CMP1P.10
13	P2.3	Multifunction I/O	Yes	EMIF_A11	ADC0.19 CMP0N.9 CMP1N.9
14	P2.2	Multifunction I/O	Yes	EMIF_A10	ADC0.18 CMP0P.9 CMP1P.9
15	P2.1	Multifunction I/O	Yes	EMIF_A9	ADC0.17 CMP0N.8 CMP1N.8
16	P2.0	Multifunction I/O	Yes	EMIF_A8	ADC0.16 CMP0P.8 CMP1P.8
17	P1.7	Multifunction I/O	Yes	P1MAT.7 EMIF_AD7	ADC0.15 CMP0N.7 CMP1N.7
18	P1.6	Multifunction I/O	Yes	P1MAT.6 EMIF_AD6	ADC0.14 CMP0P.7 CMP1P.7

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
30	P0.2	Multifunction I/O	Yes	P0MAT.2 INT0.2 INT1.2	ADC0.2 CMP0P.1 CMP1P.1 XTAL1
31	P0.1	Multifunction I/O	Yes	P0MAT.1 INT0.1 INT1.1	ADC0.1 AGND CMP0N.0 CMP1N.0
32	P0.0	Multifunction I/O	Yes	P0MAT.0 INT0.0 INT1.0	ADC0.0 CMP0P.0 CMP1P.0 VREF
Center	GND	Ground			

6.2 EFM8SB2x-QFN24 Pin Definitions

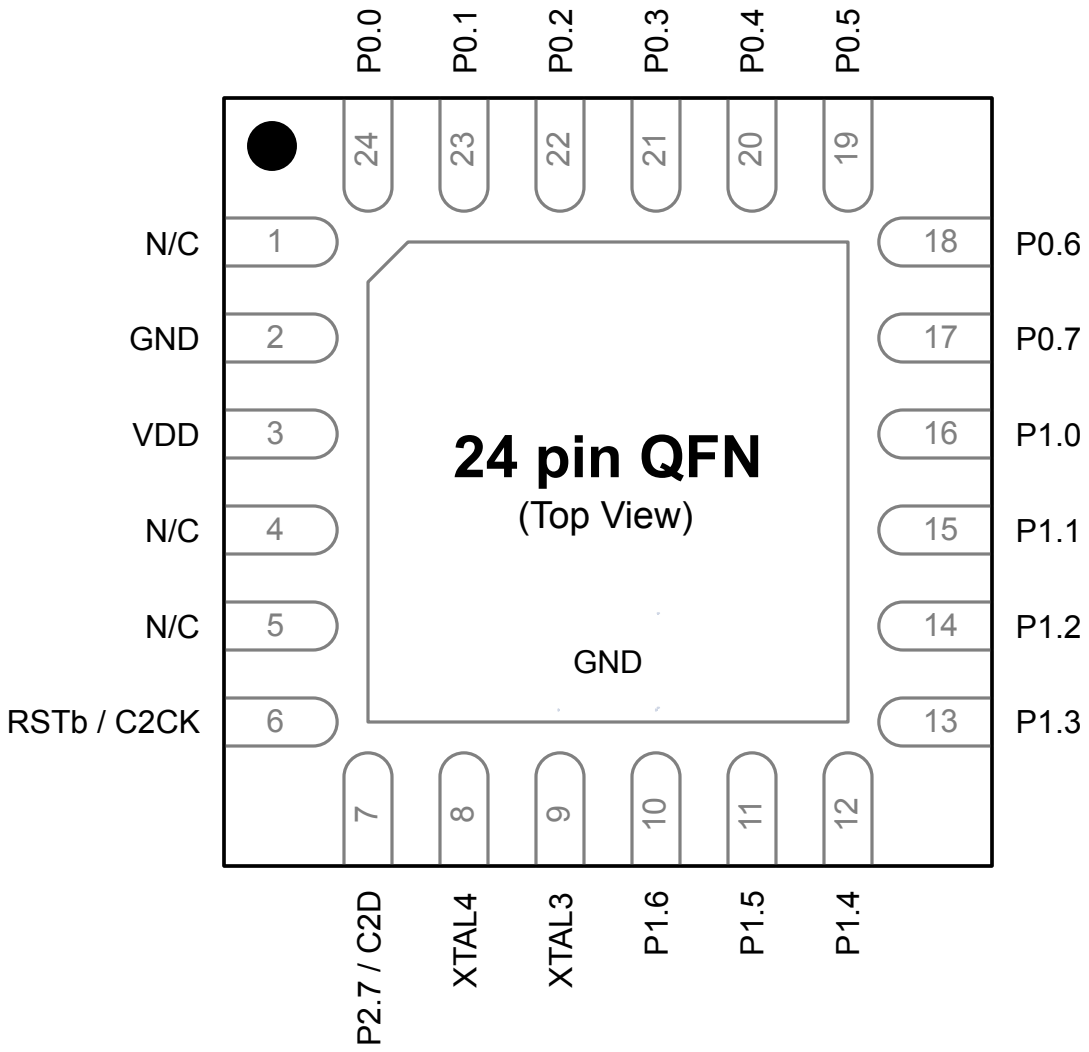

Figure 6.2. EFM8SB2x-QFN24 Pinout

Table 6.2. Pin Definitions for EFM8SB2x-QFN24

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
1	N/C	No Connection			
2	GND	Ground			
3	VDD	Supply Power Input			
4	N/C	No Connection			
5	N/C	No Connection			

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
6	RSTb / C2CK	Active-low Reset / C2 Debug Clock			
7	P2.7 / C2D	Multifunction I/O / C2 Debug Data			
8	XTAL4	RTC Crystal			XTAL4
9	XTAL3	RTC Crystal			XTAL3
10	P1.6	Multifunction I/O	Yes		ADC0.14 CMP0P.7 CMP1P.7
11	P1.5	Multifunction I/O	Yes	P1MAT.5	ADC0.13 CMP0N.6 CMP1N.6
12	P1.4	Multifunction I/O	Yes	P1MAT.4	ADC0.12 CMP0P.6 CMP1P.6
13	P1.3	Multifunction I/O	Yes	P1MAT.3 SPI1_NSS	ADC0.11 CMP0N.5 CMP1N.5
14	P1.2	Multifunction I/O	Yes	P1MAT.2 SPI1_MOSI	ADC0.10 CMP0P.5 CMP1P.5
15	P1.1	Multifunction I/O	Yes	P1MAT.1 SPI1_MISO	ADC0.9 CMP0N.4 CMP1N.4
16	P1.0	Multifunction I/O	Yes	P1MAT.0 SPI1_SCK	ADC0.8 CMP0P.4 CMP1P.4
17	P0.7	Multifunction I/O	Yes	P0MAT.7 INT0.7 INT1.7	ADC0.7 IREF0 CMP0N.3 CMP1N.3
18	P0.6	Multifunction I/O	Yes	P0MAT.6 CNVSTR INT0.6 INT1.6	ADC0.6 CMP0P.3 CMP1P.3

6.3 EFM8SB2x-QFP32 Pin Definitions

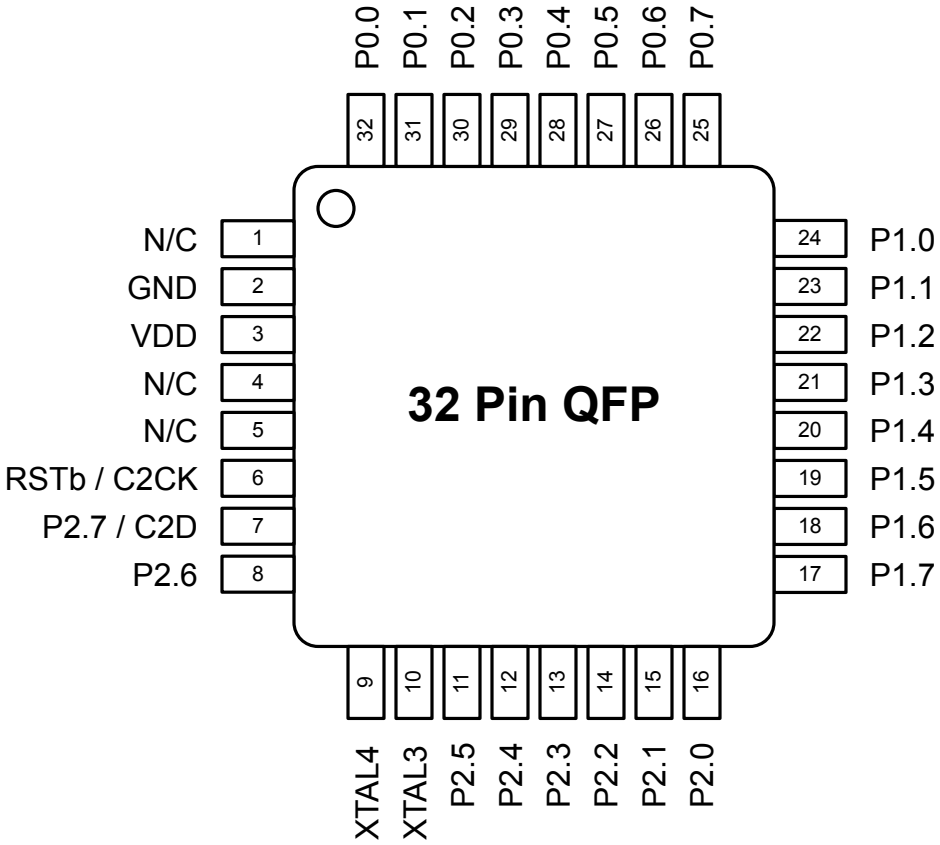

Figure 6.3. EFM8SB2x-QFP32 Pinout

Table 6.3. Pin Definitions for EFM8SB2x-QFP32

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
1	N/C	No Connection			
2	GND	Ground			
3	VDD	Supply Power Input			
4	N/C	No Connection			
5	N/C	No Connection			
6	RSTb / C2CK	Active-low Reset / C2 Debug Clock			
7	P2.7 / C2D	Multifunction I/O / C2 Debug Data			

8.2 QFN24 PCB Land Pattern

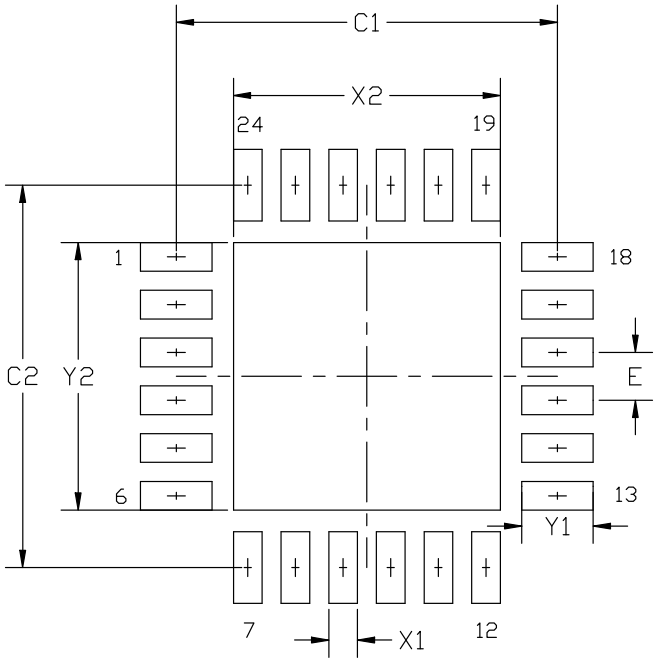

Figure 8.2. QFN24 PCB Land Pattern Drawing

Table 8.2. QFN24 PCB Land Pattern Dimensions

Dimension	Min	Max
C1	3.90	4.00
C2	3.90	4.00
E	0.50 BSC	
X1	0.20	0.30
X2	2.70	2.80
Y1	0.65	0.75
Y2	2.70	2.80

Dimension	Min	Max

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
5. The stencil thickness should be 0.125 mm (5 mils).
6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
7. A 2 x 2 array of 1.10 mm x 1.10 mm openings on 1.30 mm pitch should be used for the center ground pad.
8. A No-Clean, Type-3 solder paste is recommended.
9. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

8.3 QFN24 Package Marking

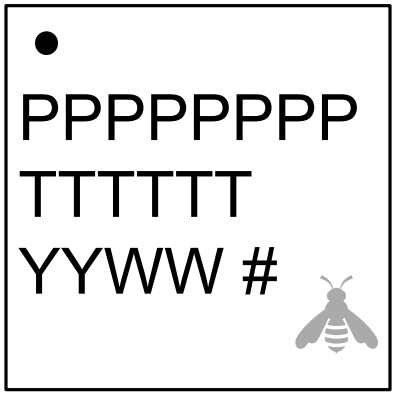

Figure 8.3. QFN24 Package Marking

The package marking consists of:

- PPPPPPPP – The part number designation.
- TTTTTT – A trace or manufacturing code.
- YY – The last 2 digits of the assembly year.
- WW – The 2-digit workweek when the device was assembled.
- # – The device revision (A, B, etc.).

9.2 QFP32 PCB Land Pattern

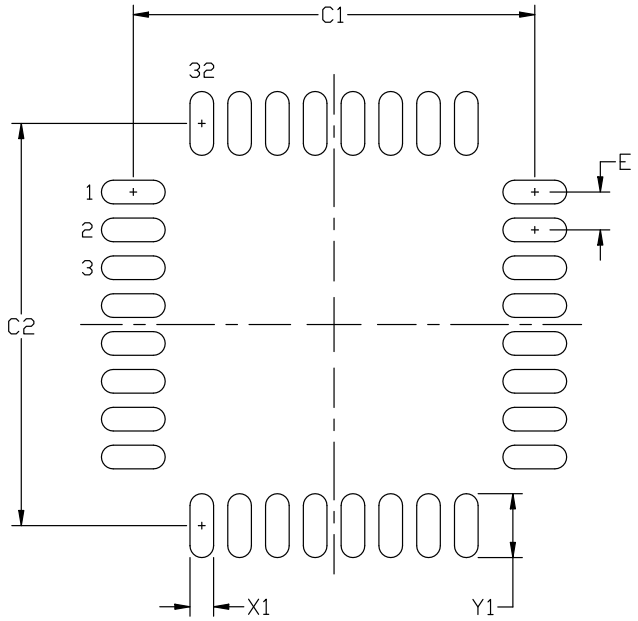

Figure 9.2. QFP32 PCB Land Pattern Drawing

Table 9.2. QFP32 PCB Land Pattern Dimensions

Dimension	Min	Max
C1	8.40	8.50
C2	8.40	8.50
E	0.80 BSC	
X1	0.40	0.50
Y1	1.25	1.35

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
5. The stencil thickness should be 0.125 mm (5 mils).
6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
7. A No-Clean, Type-3 solder paste is recommended.
8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

Table of Contents

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